

Features

- Operating voltage: 2.7V–5.5V
- Low power consumption
 - Operation: 25mA Max. ($V_{CC}=5V$)
10mA Max. ($V_{CC}=3V$)
 - Standby: 30 μ A Max. ($V_{CC}=5V$)
10 μ A Max. ($V_{CC}=3V$)
- Access time: 150ns Max. ($V_{CC}=5V$)
250ns Max. ($V_{CC}=3V$)
- 131072×8 bits of mask ROM
- Mask options: chip enable $\overline{CE}/\overline{OE1}/\overline{OE1B}$ and output enable $\overline{OE}/\overline{NC}$
- TTL compatible inputs and outputs
- Tristate outputs
- Fully static operation
- Package type: 28-pin DIP/SOP
32-pin DIP/SOP/PLCC

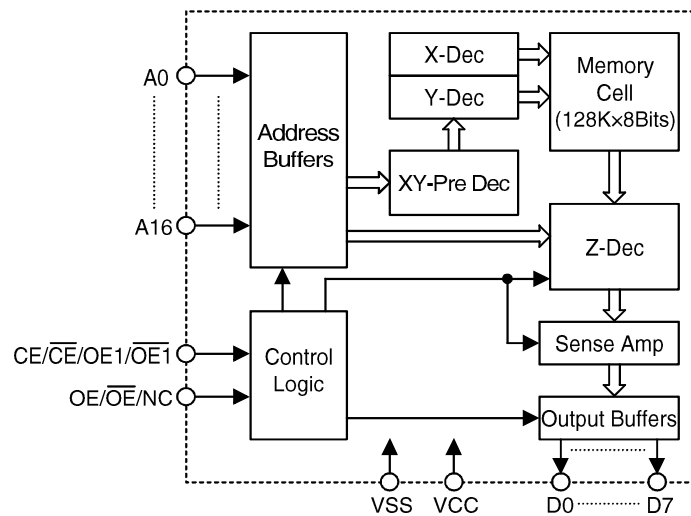
General Description

The HT23C010 is a read-only memory with high performance CMOS storage device whose 1024K of memory is arranged into 131072 words by 8 bits.

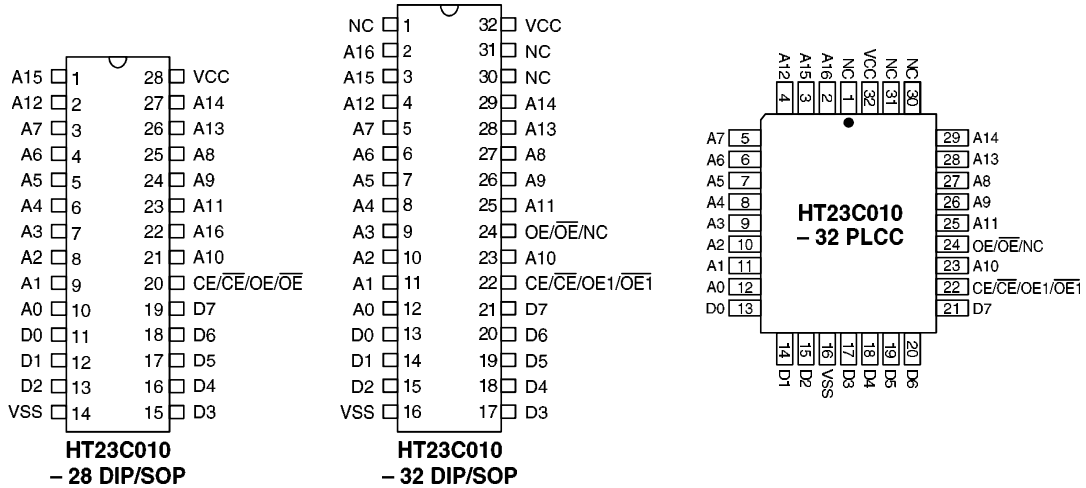
For application flexibility, the chip enable and output enable control pins can be selected as active high or active low. This flexibility not only allows easy interface with most microprocessors, but also eliminates bus contention in

multiple bus microprocessor systems. An additional feature of the HT23C010 is its ability to enter the standby mode whenever the chip enable ($\overline{CE}/\overline{OE}$) is inactive, thus reducing current consumption to below 30 μ A. The combination of these functions makes the chip suitable for high density low power memory applications.

Block Diagram



Pin Assignment



Pin Description

| Pin Name | I/O | Description |
|--|-----|---------------------------------|
| A0~A16 | I | Address inputs |
| D0~D7 | O | Data outputs |
| CE/ $\overline{\text{CE}}$ /OE1/ $\overline{\text{OE1}}$ | I | Chip enable output enable input |
| VSS | I | Negative power supply |
| VCC | I | Positive power supply |
| OE/ $\overline{\text{OE}}$ /NC | I | Output enable input |
| NC | — | No connection |

Operation Truth Table

| Mode | CE/ $\overline{\text{CE}}$ | OE/ $\overline{\text{OE}}$ | A0~A16 | D0~D7 |
|----------|----------------------------|----------------------------|--------|----------|
| Read | H/L | H/L | Valid | Data Out |
| Deselect | H/L | L/H | X | High Z |
| Standby | L/H | X | X | High Z |

Note: H= V_{IH} , L= V_{IL} , X= V_{IH} or V_{IL}

Absolute Maximum Ratings*

Supply Voltage -0.3V to 6V Storage Temperature..... -50°C to 125°C
 Input Voltage..... -0.3V to $V_{CC}+0.3V$ Operating Temperature..... -40°C to 85°C

*Note: These are stress ratings only. Stresses exceeding the range specified under “Absolute Maximum Ratings” may cause substantial damage to the device. Functional operation of this device at other conditions beyond those listed in the specification is not implied and prolonged exposure to extreme conditions may affect device reliability.

D.C. Characteristics
Supply voltage: 2.7V~3.6V
 $T_a = -40^\circ\text{C}$ to 85°C

| Symbol | Parameter | Test Conditions | | Min. | Typ. | Max. | Unit |
|-------------------|-------------------------------|-----------------|--|-----------------|------|-----------------|------|
| | | VCC | Conditions | | | | |
| V _{CC} | Operating Voltage | — | — | 2.7 | — | 3.6 | V |
| I _{CC} | Operating Current | 3V | O/P Unload, f=5MHz | — | — | 10 | mA |
| V _{IL} | Input Low Voltage | 3V | — | V _{SS} | — | 0.4 | V |
| V _{IH} | Input High Voltage | 3V | — | 2.0 | — | V _{CC} | V |
| V _{OL} | Output Low Voltage | 3V | I _{OL} =2.1mA | — | — | 0.4 | V |
| V _{OH} | Output High Voltage | 3V | I _{OH} =-0.4mA | 2.4 | — | V _{CC} | V |
| I _{LI} | Input Leakage Current | 3V | V _{IN} =0 to V _{CC} | — | — | 10 | μA |
| I _{LO} | Output Leakage Current | 3V | V _{OUT} =0 to V _{CC} | — | — | 10 | μA |
| I _{STB1} | Standby Current | 3V | $\frac{CE=V_{IL}}{CE=V_{IH}}$ | — | — | 500 | μA |
| I _{STB2} | Standby Current | 3V | $\frac{CE \leq 0.2V}{CE \geq V_{CC}-0.2V}$ | — | — | 10 | μA |
| C _{IN} | Input Capacitance (See note) | — | f=1MHz | — | — | 10 | pF |
| C _{OUT} | Output Capacitance (See note) | — | f=1MHz | — | — | 10 | pF |

Note: These parameters are periodically sampled but not 100% tested.

Supply voltage: 4.5V~5.5V
 $T_a = -40^\circ\text{C}$ to 85°C

| Symbol | Parameter | Test Conditions | | Min. | Typ. | Max. | Unit |
|-----------------|-------------------|-----------------|-----------------------|------|------|------|------|
| | | VCC | Conditions | | | | |
| V _{CC} | Operating Voltage | — | — | 4.5 | — | 5.5 | V |
| I _{CC} | Operating Current | 5V | O/P Unload, f=5MHz | — | — | 25 | mA |

| Symbol | Parameter | Test Conditions | | Min. | Typ. | Max. | Unit |
|-------------------|-------------------------------|-----------------|--|-----------------|------|-----------------|------|
| | | VCC | Conditions | | | | |
| V _{IL} | Input Low Voltage | 5V | — | V _{SS} | — | 0.8 | V |
| V _{IH} | Input High Voltage | 5V | — | 2.2 | — | V _{CC} | V |
| V _{OL} | Output Low Voltage | 5V | I _{OL} =3.2mA | — | — | 0.4 | V |
| V _{OH} | Output High Voltage | 5V | I _{OH} =-1mA | 2.4 | — | V _{CC} | V |
| I _{LI} | Input Leakage Current | 5V | V _{IN} =0 to V _{CC} | — | — | 10 | μA |
| I _{LO} | Output Leakage Current | 5V | V _{OUT} =0 to V _{CC} | — | — | 10 | μA |
| I _{STB1} | Standby Current | 5V | $\frac{CE=V_{IL}}{CE=V_{IH}}$ | — | — | 1.5 | mA |
| I _{STB2} | Standby Current | 5V | $\frac{CE \leq 0.2V}{CE \geq V_{CC}-0.2V}$ | — | — | 30 | μA |
| C _{IN} | Input Capacitance (See note) | — | f=1MHz | — | — | 10 | pF |
| C _{OUT} | Output Capacitance (See note) | — | f=1MHz | — | — | 10 | pF |

Note: These parameters are periodically sampled but not 100% tested.

A.C. Characteristics

T_a=-40°C to 85°C

| Symbol | Parameter | VCC=2.7V~3.6V | | VCC=4.5V~5.5V | | Unit |
|------------------|--------------------------------|---------------|------|---------------|------|------|
| | | Min. | Max. | Min. | Max. | |
| t _{CYC} | Cycle Time | 250 | — | 150 | — | ns |
| t _{AA} | Address Access Time | — | 250 | — | 150 | ns |
| t _{ACE} | Chip Enable Access Time | — | 250 | — | 150 | ns |
| t _{AOE} | Output Enable Access Time | — | 150 | — | 80 | ns |
| t _{OH} | Output Hold Time | — | — | 10 | — | ns |
| t _{OD} | Output Disable Time (See Note) | — | — | — | 70 | ns |
| t _{OE} | Output Enable Time (See Note) | — | — | 10 | — | ns |

Note: These parameters are periodically sampled but not 100% tested.

A.C. test conditions

Output load: see figure right

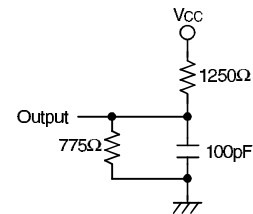
Input rise and fall time: 10ns

Input pulse levels: 0.4V to 2.4V (V_{CC}=5V)

Input and output timing reference levels:

0.8V and 2.0V (V_{CC}=5V)

1.5V (V_{CC}=3V)



* Including scope and jig

Output load circuit

Functional Description

The HT23C010 has two modes, namely data read mode and standby mode, controlled by $\overline{CE}/\overline{OE1}/\overline{OE1}$ and $\overline{OE}/\overline{OE}/\overline{NC}$ inputs.

- Standby mode

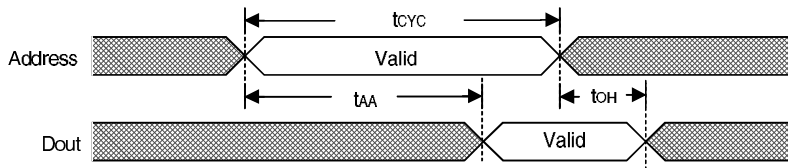
The HT23C010 offers lower current consumption, controlled by the chip enable input ($\overline{CE}/\overline{CE}$). When a low/high level is applied to the $\overline{CE}/\overline{CEB}$ input regardless of the output enable ($\overline{OE}/\overline{OE}/\overline{NC}$) states the chip will enter the standby mode.

- Data read mode

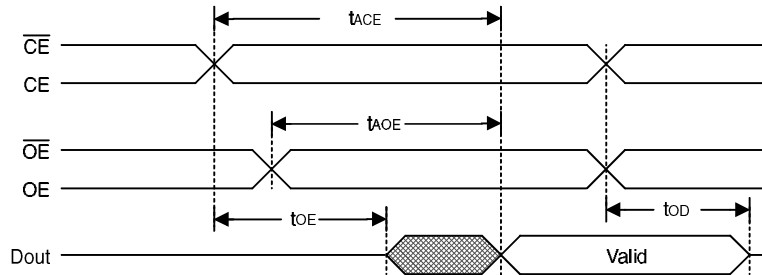
When both the chip enable ($\overline{CE}/\overline{CE}/\overline{OE1}/\overline{OE1}$) and the output enable ($\overline{OE}/\overline{OE}/\overline{NC}$) are active, the chip is in data read mode. Otherwise, active $\overline{CE}/\overline{CE}$ and inactive $\overline{OE}/\overline{OE}/\overline{NC}$ result in deselect mode. The output will remain in Hi-Z state.

Timing Diagrams

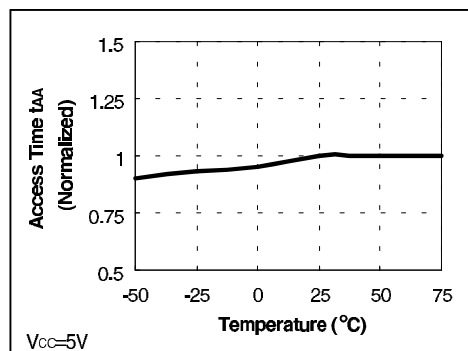
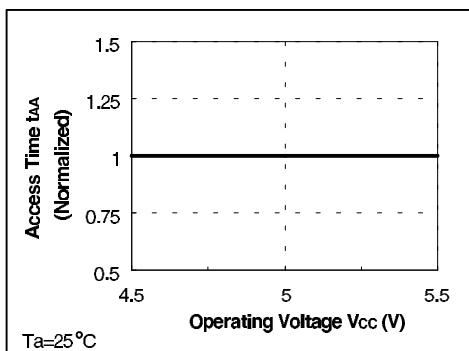
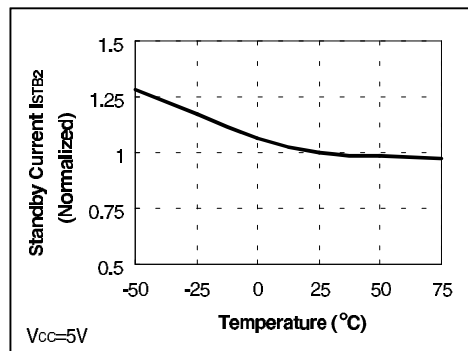
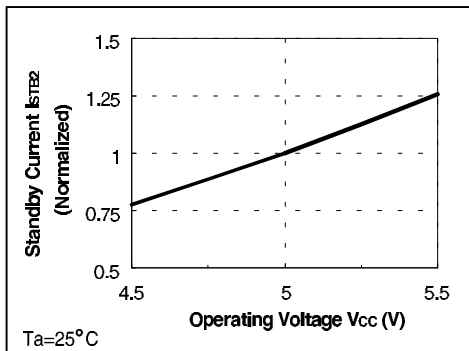
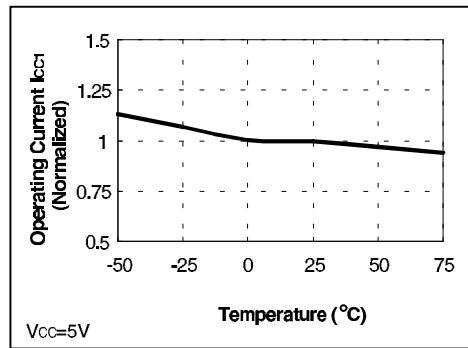
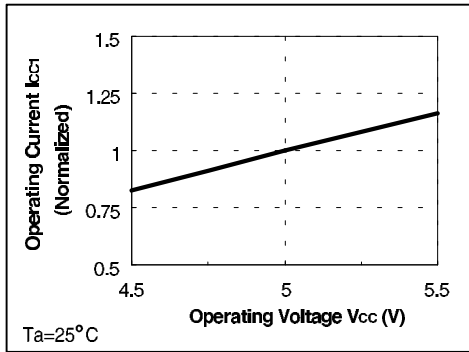
- Propagation delay due to address ($\overline{CE}/\overline{CE}/\overline{OE1}/\overline{OE1}$ and $\overline{OE}/\overline{OE}$ are active)

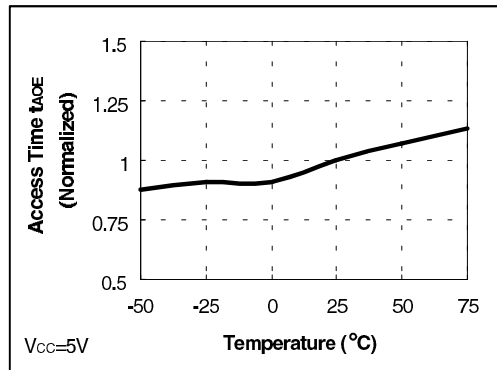
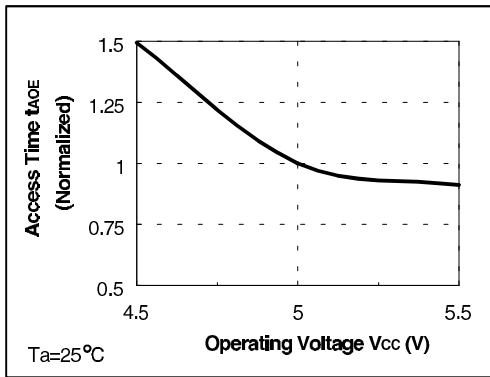
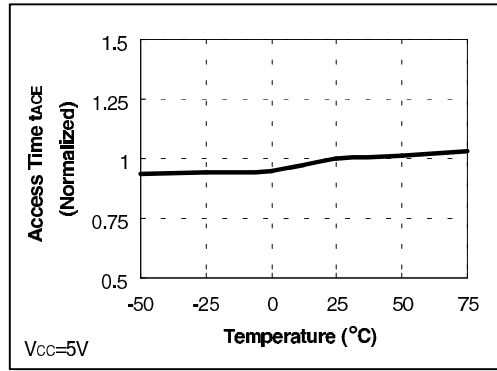
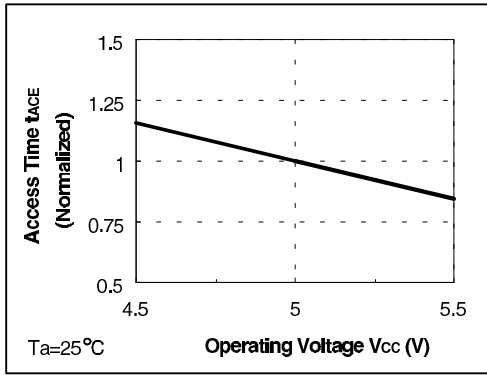


- Propagation delay due to chip and output enable (address valid)



Characteristic Curves





HT23C010 MASK ROM ORDERING SHEET

Custom: _____

Input Medium:

EPROM DISK File (Mail Address: romfile@holtek.com.tw) OTHER _____

| User No. | Type/Ref. Name | Q'ty | Check Sum | Memory Address | |
|----------|----------------|------|-----------|----------------|-----|
| | | | | Start | End |
| | | | | | |

Control Pin and Package Form Option:

(a) I. 28 Pin Type Pin 20: _____ (1) CE (2) \overline{CE} (3) OE (4) \overline{OE}
 II. 32 Pin Type Pin 22: _____ (1) CE (2) \overline{CE} (3) OE1 (4) $\overline{OE1}$
 Pin 24: _____ (1) OE (2) \overline{OE} (3) NC

(b) Package Form: _____ (1) Chip Form (2) 28 DIP (3) 28 SOP (4) 32 DIP (5) 32 SOP
 (6) 32 PLCC

Companion User No. _____

Package Marking : _____

Delivery Date : _____ Q'ty: _____

CUSTOM CONFIRMED BY:

 (NAME, DATE, POSITION & CO. CHOP)

HOLTEK CONFIRMED BY:

 (SALES)

 (SALES MANAGER)